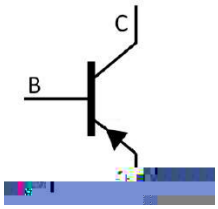
TO-92 PNP Silicon PNP transistor in a TO-92 Plastic Package.

High voltage.

High voltage control circuit application.

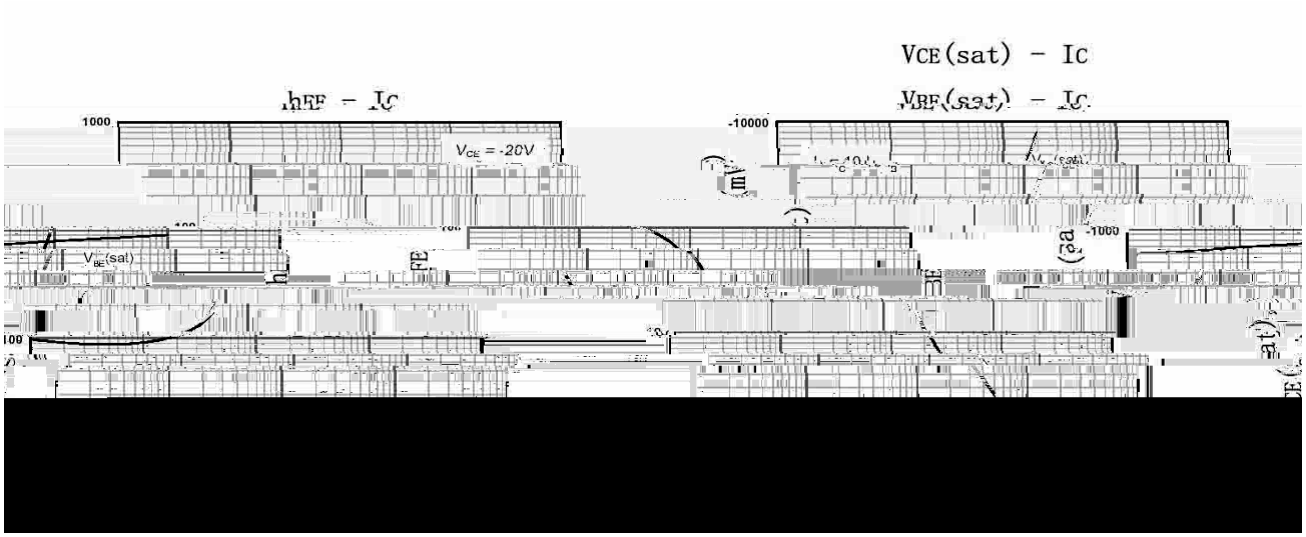


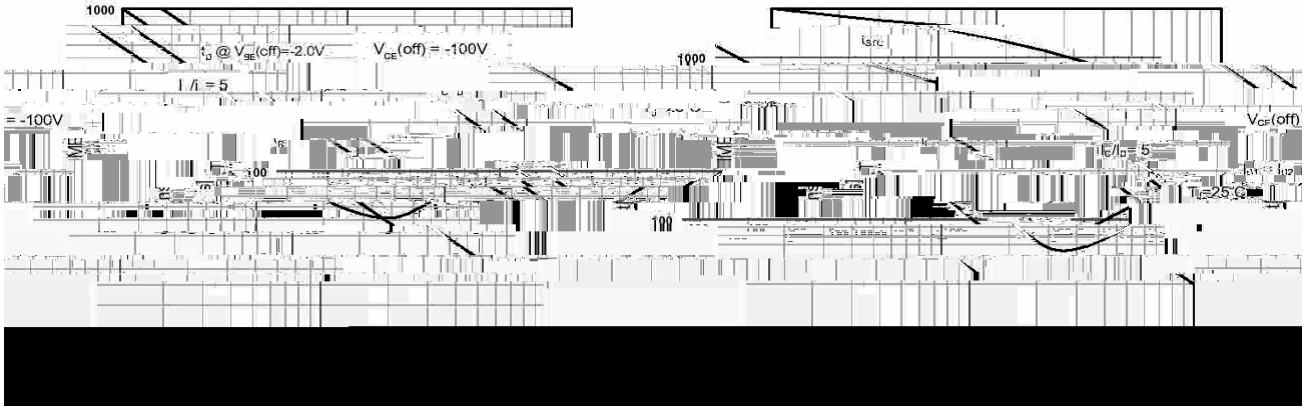


PIN1 Collector PIN 2 Base PIN 3 Emitter

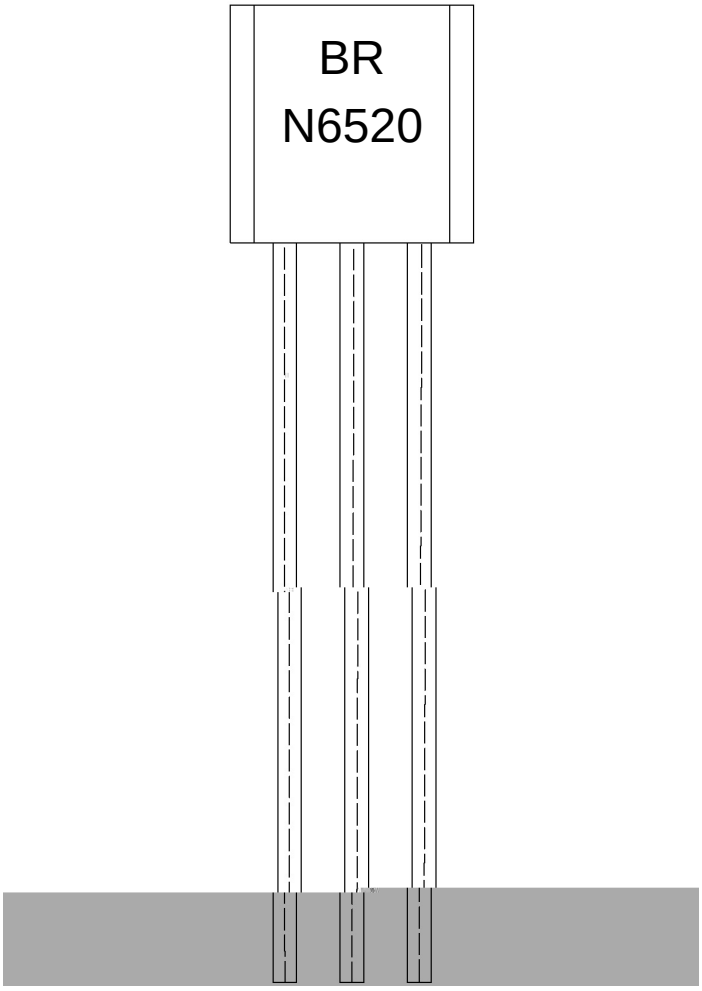
See Marking Instructions.

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-350	V
Collector to Emitter Voltage	V_{CEO}	-350	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-500	mA
Base Current - Continuous	I_B	-250	mA
Collector Power Dissipation	P_C	625	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	


VCE(sat) - Ic
1000
VCE = -20V
-10000
-1000


1000
VCE(off) = -100V
1000
VCE(off)
TC=25°C

Cib - VCB



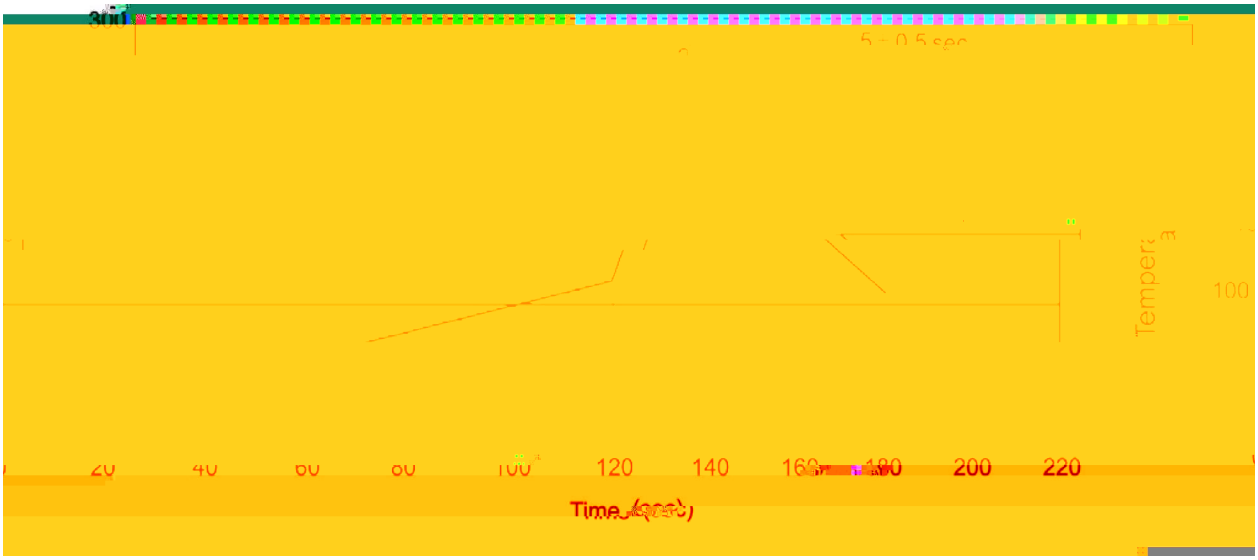
BR

N6520

****

Note:

BR:	Company Code.
N6520:	Product Type.
****:	Lot No. Code, code change with Lot No.



						Note:	
1		25	150		60	90sec;	1.Preheating:25~150 , Time:60~90sec.
2		255±5				5±0.5sec;	2.Peak Temp.:255±5 , Duration:5±0.5sec.
3				2	10	/sec.	3. Cooling Speed: 2~10 /sec.

270±5	10±1 sec.	Temp.:270±5